BT151X series Thyristors

Rev. 5 — 1 November 2011

Product data sheet

1. Product profile

1.1 General description

Passivated thyristors in a SOT186A full pack plastic package.

1.2 Features and benefits

- High thermal cycling performance
- High bidirectional blocking voltage capability

1.3 Applications

Motor control

1.4 Quick reference data

- V_{DRM}, V_{RRM} ≤ 800 V (BT151X-800)
- V_{DRM}, V_{RRM} ≤ 650 V (BT151X-650)
- V_{DRM}, V_{RRM} ≤ 500 V (BT151X-500)
- 2. Pinning information

Table 1.	Discrete pinning		
Pin	Description	Simplified outline	Symbol
1	cathode (K)	mb	
2	anode (A)		А
3	gate (G)		G sym037
mb	mounting base; isolated		





- Isolated mounting base.
- Industrial and domestic lighting, heating and static switching.
- I_{T(RMS)} ≤ 12 A
- I_{T(AV)} \leq 7.5 A
- $\blacksquare I_{TSM} \le 120 \text{ A}.$

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3. Ordering information

Table 2. Ordering information						
Type number	Package	age				
	Name	Description	Version			
BT151X-500	-	plastic single-ended package; isolated heatsink mounted; 1 mounting hole;	SOT186A			
BT151X-650		3 lead TO-220 'full pack'				
BT151X-800						

4. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

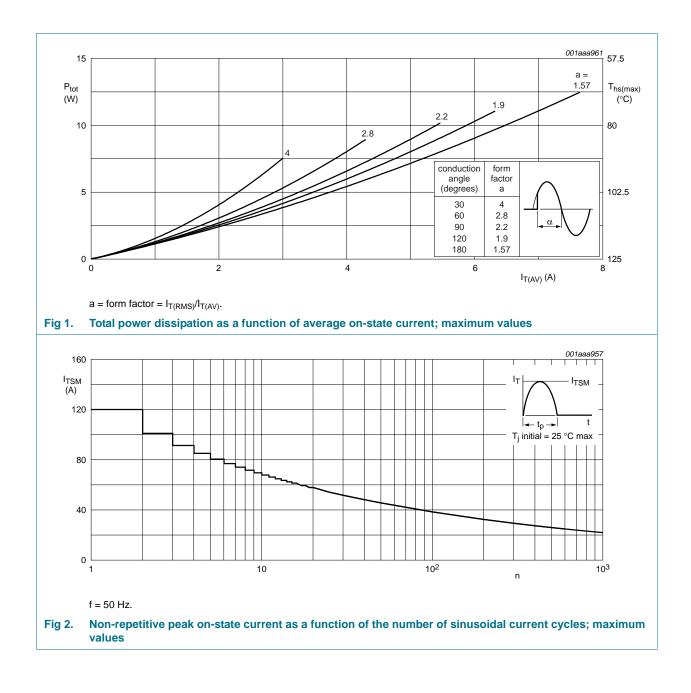
Symbol	Parameter	Conditions		Min	Max	Unit
V _{DRM} , V _{RRM}	repetitive peak off-state voltage					
	BT151X-500		[1]	-	500	V
	BT151X-650		<u>[1]</u>	-	650	V
	BT151X-800			-	800	V
I _{T(AV)}	average on-state current	half sinewave; T _{hs} ≤ 69 °C; <u>Figure 1</u>		-	7.5	А
I _{T(RMS)}	RMS on-state current	all conduction angles; Figure 4 and Figure 5		-	12	A
I _{TSM}	non-repetitive peak on-state current	half sinewave; $T_j = 25 \text{ °C prior to}$ surge; <u>Figure 2</u> and <u>Figure 3</u>				
		t = 10 ms		-	120	А
		t = 8.3 ms		-	132	А
l ² t	I ² t for fusing	t = 10 ms		-	72	A ² s
dl _T /dt	repetitive rate of rise of on-state current after triggering	I_{TM} = 20 A; I_G = 50 mA; dI _G /dt 50 mA/µs		-	50	A/μs
I _{GM}	peak gate current			-	2	А
V _{RGM}	peak reverse gate voltage			-	5	V
P _{GM}	peak gate power			-	5	W
P _{G(AV)}	average gate power	over any 20 ms period		-	0.5	W
T _{stg}	storage temperature			-40	+150	°C
T _j	junction temperature			-	125	°C

[1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 $A/\mu s$.

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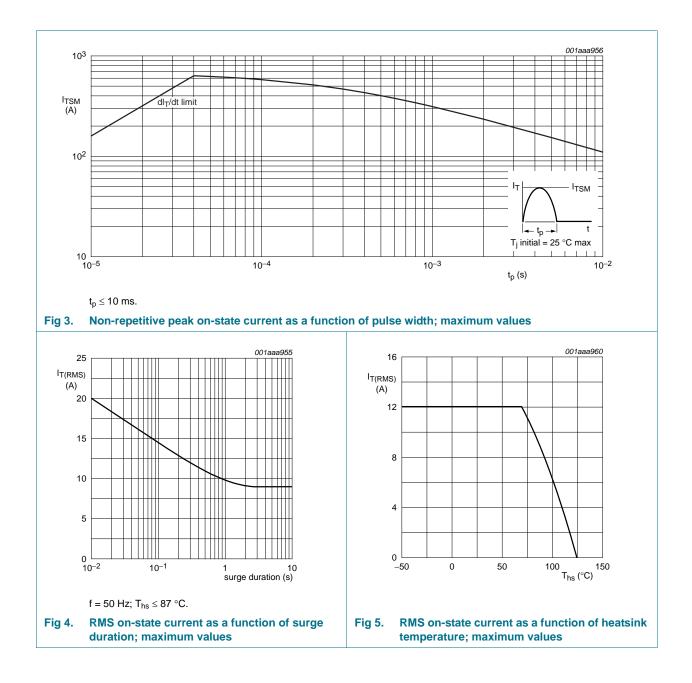


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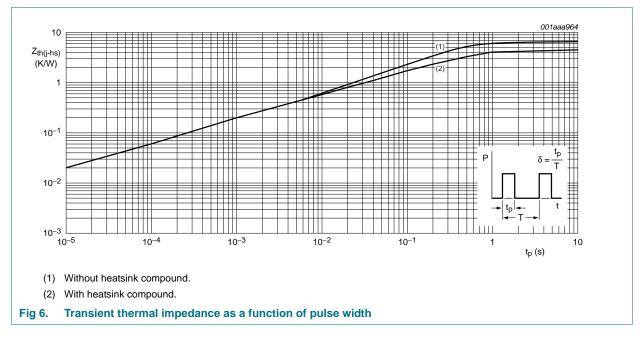
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5. Thermal characteristics

Table 4.	Thermal characteristics				
Symbol	Parameter	Conditions	Тур	Max	Unit
R _{th(j-hs)}	thermal resistance from junction to heatsink	Figure 6			
		with heatsink compound	-	4.5	K/W
		without heatsink compound	-	6.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	55	-	K/W



6. Isolation characteristics

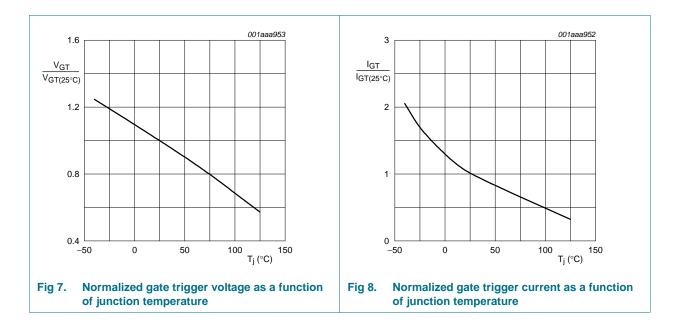
Table 5. Isolation limiting values and characteristics

$T_{hs} = 25 \ ^{\circ}C$ unless otherwise specified					
Symbol	Parameter	Conditions	Тур	Max	Unit
V _{isol}	RMS isolation voltage from all three terminals to external heatsink	f = 50 to 60 Hz; sinusoidal waveform; R.H. \leq 65%; clean and dust free	-	2500	V
C _{isol}	capacitance from pin 2 to external heatsink	f = 1 MHz	10	-	pF

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7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; <u>Figure 8</u>	-	2	15	mA
IL	latching current	V _D = 12 V; I _{GT} = 0.1 A; <u>Figure 10</u>	-	10	40	mA
I _H	holding current	V _D = 12 V; I _{GT} = 0.1 A; <u>Figure 11</u>	-	7	20	mA
V _T	on-state voltage	I _T = 23 A; <u>Figure 9</u>	-	1.4	1.75	V
V _{GT}	gate trigger voltage	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \frac{\text{Figure 7}}{100000000000000000000000000000000000$	-	0.6	1.5	V
		$V_D = V_{DRM(max)}$; $I_T = 0.1 A$; $T_j = 125 \ ^{\circ}C$	0.25	0.4	-	V
I _D , I _R	off-state leakage current	$V_D = V_{DRM(max)}; V_R = V_{RRM(max)};$ $T_j = 125 \text{ °C}$	-	0.1	0.5	mA
Dynamic o	characteristics					
dV _D /dt	critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$ exponential waveform; <u>Figure 12</u>				
		gate open circuit	50	130	-	V/µs
		R _{GK} = 100 Ω	200	1000	-	V/μs
t _{gt}	gate controlled turn-on time	$I_{TM} = 40 \text{ A}; V_D = V_{DRM(max)};$ $I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A}/\mu \text{s}$	-	2	-	μS
t _q	circuit commuted turn-on time		-	70	-	μS



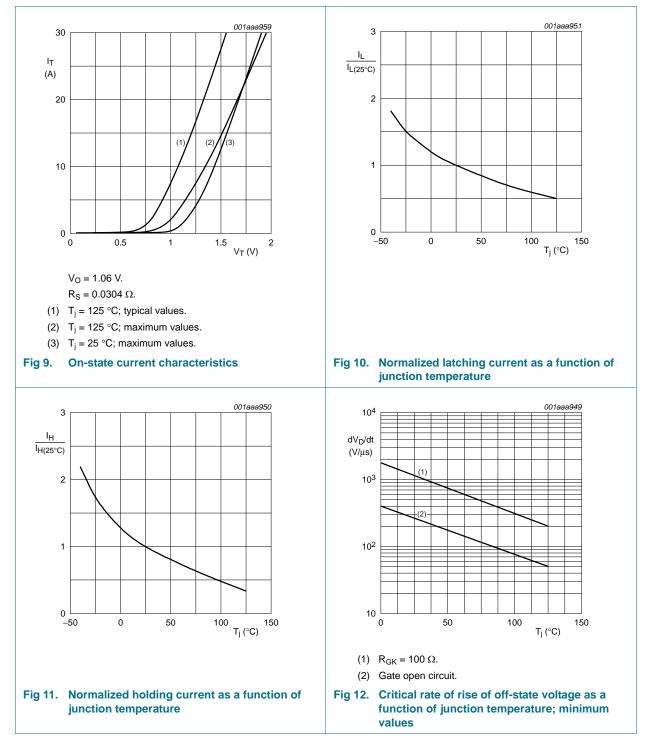
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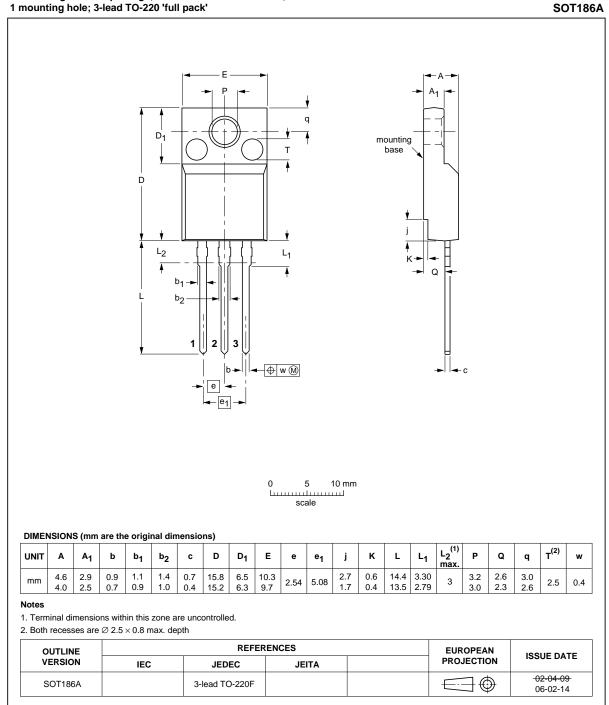
8. Package information

Epoxy meets requirements of UL94 V-0 at $\frac{1}{8}$ inch.

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Package outline 9.



Plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 'full pack'

Fig 13. Package outline SOT186A (TO-220)

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10. Revision history

Table 7. Revision his	story			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BT151X_SER v.5	20111101	Product data sheet		BT151X_SERIES v.4
Modifications:		of this data sheet has beer f NXP Semiconductors.	redesigned to comply w	vith the new identity
	 Legal texts I 	have been adapted to the r	new company name whe	re appropriate.
BT151X_SERIES v.4	20040609	Product data sheet		BT151X_SERIES v.3
BT151X_SERIES v.3	20030901	Product specification		BT151X_SERIES v.2
BT151X_SERIES v.2	19990601	Product specification		BT151X_SERIES v.1
BT151X_SERIES v.1	19970901	Product specification		-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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